STUDY ON HYDROGENATED CARBON ATOM CHAINS WITH NEGATIVE DIFFERENTIAL RESISTANCE EFFECT.

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Abstract

Using first-principles calculations combined with a nonequilibrium Green's function method, we investigate the transport properties of four carbon chains connected to armchair carbon nanotubes. At very low bias voltage, a strong negative differential resistance effect is present. Moreover, such effect can be modified by using different radicals in the terminal of carbon chain. This paper realizes that not only "odd" carbon chains can induce negative differential resistance effect, which indicate potential applications in nanomolecular-electronics.

Introduction:

Molecular electronics is the use of molecules as the primary building block for electronic circuitry. Because of significantly decreasing device size, it would be a useful candidate for the traditional Si-based electronics. Many experimental and theoretical works demonstrated that molecule systems could be a new technological platform for electronic devices[1-15]. Recently, Yuzvinsky et al.16] and Chuvilin et al.17] show that carbon chains could be realized through graphene nanoribbons and carbon nanotubes. Several researches18-24] reveal that some carbon-chain-based devices have negative differential resistance (NDR) effect. NDR effect is characterized by the decreases in current as the bias increases in some specific bias range. Berg et al.25] report that the NDR effect is valuable and practical only under low bias. Unfortunately, this effect only occurs if the number of carbon chain atoms on both side of the barrier is all odd20, 23]. Moreover, it is difficult to prepare such "odd" molecules20]. So, the probability of the NDR effect for molecular device under low bias is only 1/2 x 1/2.

In order to remove the restriction of "odd" chain, we attempt to induce the molecular NDR effect at low bias by the hydrogenated terminal carbon atom in this paper. Using first-principles calculations combined with nonequilibrium Green's function (NEGF) method and the density functional theory (DFT), we investigate the transport properties of four carbon chains connected to armchair carbon nanotubes. We find that the molecular NDR effect at low bias is absent when the terminal radical of carbon chain is –CH and present when that is –CH₂ and –CH₃. Generalize to the case of "odd" carbon chains, according to the Octet rule20, the molecular NDR effect at low bias will be absent when the terminal radical of carbon chain is –CH and present when that is –CH and –CH₂. Therefore, the probability of the molecular NDR effect at low bias for molecular devices proposed by us increases to 2/3 x 2/3. This probability will further increase when scanning tunneling microscopy (STM) or atomic force microscopy (AFM)26-28] is used to help hydrogenated reaction because the demanded radical can be obtained if the amount of hydrogen atom adsorbed on probe and the contact time between the probe and the carbon chain are selectively controlled.

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Computational details
Fig.1 shows the molecular transport systems (TSs). Two carbon chains with four atoms contact the left and right leads of (6,6) carbon nanotube, respectively. These three TSs are similar except different terminal radical in the carbon chains. From Fig.1(a) to 1(c), the terminal radical is –CH, –CH$_2$ and –CH$_3$, respectively. In the following, we call these three TSs from Fig.1(a) to 1(c) are –CH terminal, –CH$_2$ terminal and –CH$_3$ terminal, respectively. The whole TS contains three parts: the left and right leads, and the scattering region. The left and right leads are composed of (6, 6) carbon nanotube with four atomic layers. The carbon nanotube contacting left (right) lead in the scattering region contains five (six) atomic layers. The edge of carbon nanotube in the scattering region is hydrogenated.

Fig. 1. (Color online) Schematic illustrations of the transport systems of two capped (6, 6) carbon nanotubes sandwiching two carbon chains. (a), (b) and (c) are –CH, –CH$_2$ and –CH$_3$ terminal, respectively. Color code: C atom (black) and H atom (grey).

Our calculations are performed by the Atomistix ToolKit (ATK) package, which combines the NEGF and the DFT. A 1×1×50 k-points sampling is used throughout the calculation and the cutoff energy is set to 250Ry. For all C and H atoms, we choose a single-ζ plus polarization basis. The local density approximation with the Perdew and Zunger form is adopted for the exchange-correlation functional. The formula (1) is used to describe the current through the scattering region,

$$ I = \frac{2e}{\hbar} \int_{-\infty}^{\infty} T(V_b, E)[f_L(E - \mu_L) - f_R(E - \mu_r)]dE $$

where $\hbar$ the plank constant and $e$ is the electron charge. $f_L(R)$ is the Fermi-Dirac distribution for left (right) lead, $\mu_L(R)$ is the corresponding electrochemical potential. $T(V_b, E)$ is transmission coefficient.

$$ T(V_b, E) = Tr[\Gamma_L(V_b, E)G(V_b, E)\Gamma_R(V_b, E)G^+(V_b, E)] $$

Results and discussions:
Fig.2 shows the current-voltage ($I$-$V$) curve of –CH terminal, –CH$_2$ terminal and –CH$_3$ terminal, respectively. In Fig.2, the molecular NDR effect at low bias is present for –CH$_2$ terminal and –CH$_3$ terminal while absent for –CH terminal. The current for –CH terminal is almost inhibited all over bias region. The peak position of bias ($V_{peak}$) corresponding to the peak position of current ($I_{peak}$) for –CH$_2$ (-CH$_3$) terminal is 0.20 V (0.34 V) while the valley
position of bias ($V_{\text{valley}}$) corresponding to the valley position of current ($I_{\text{valley}}$) for $-\text{CH}_2$ ($-\text{CH}_3$) terminal is 1.16 V (1.42 V). It should be mentioned here that the molecular NDR effect at low bias also present in carbon atom chains sandwiched between two graphene nanoribbon [34-36]. The peak-to-valley ratio (the ratio of $I_{\text{peak}}$ to $I_{\text{valley}}$) for $-\text{CH}_2$ ($-\text{CH}_3$) terminal is as large as 679% (416%). The different $V_{\text{peak}}$ for $-\text{CH}_2$ and $-\text{CH}_3$ terminal also means that the molecular NDR effect at low bias can be adjusted by adjusting the modified radical, which indicate potential applications in the future.

![Graph 1](image1.png)

Fig. 2. (Color online) The current-bias curve of the transport systems.

![Graph 2](image2.png)

Fig. 3. (Color online) Equilibrium $T(V_b, E)$ spectrum of the transport systems. The Fermi level is indicated by a dashed line.

Figs. 3 shows $T(V_b, E)$ spectrum at zero bias for TSs. One can see a broad and high $T(V_b, E)$ peak around the Fermi level for $-\text{CH}_2$ and $-\text{CH}_3$ terminal while no peaks for $-\text{CH}$ terminal as shown in the Figs. In the following, we discard $-\text{CH}$ terminal because of no NDR effect. Spatial distributions of molecular orbital (MO) levels around the Fermi level are shown in Fig. 4. It is clear that these MO levels are the highest occupied MO (HOMO) and HOMO-1 for $-\text{CH}_2$ terminal while are HOMO-1, HOMO, the lowest unoccupied MO (LUMO), LUMO+1 for $-\text{CH}_3$ terminal. The HOMO and HOMO-1 of $-\text{CH}_2$ terminal tightly closes to each other in energy space and respectively locates on the left and right carbon chains in the scattering region, which is very beneficial for the resonance transmission between two vacuum separating carbon chains. The similar case is also present for the $-\text{CH}_3$ terminal. For these reasons, the zero bias $T(V_b, E)$ peak around the Fermi level for $-\text{CH}_2$ and $-\text{CH}_3$ terminal is
contributed by these MO levels around Fermi level. For the –CH₃ terminal, the resonance transmission not only presents between LUMO and LUMO+1 but also in the delocalized HOMO-1 and HOMO. Consequently, the T(Vₚ, E) peak around the Fermi level in –CH₃ terminal is higher than that in –CH₂ terminal.

Fig. 4. (Color online) spatial distributions of MO levels closed to the Fermi level at zero bias. (a), (b) are respectively HOMO-1, HOMO for –CH₂ terminal while (c), (d), (e), (f) are respectively HOMO-1, HOMO, LUMO, LUMO+1 for –CH₃ terminal.

Fig. 5. (Color online) (a) and (b) are bias-dependent T(Vₚ, E) spectra and MO levels for –CH₂ terminal, respectively. The energy region between two blue solid lines is transport window.

To penetrate the mechanism which results in the NDR effect, we study the bias-dependent T(Vₚ, E) spectra and MO levels around the Fermi level below. As represent, we only analyze the transport properties of –CH₂ terminal because the mechanism resulting in the NDR effect for –CH₃ terminal is similar with that for –CH₂ terminal except that the bias voltage will transfer the delocalized HOMO-1 and HOMO to localized orbital [21] in the –CH₃ terminal. The bias-dependent T(Vₚ, E) spectra for the –CH₂ terminal is shown in Fig. 5(a). From the Fig., one can clearly see that the T(Vₚ, E) peak around the Fermi level gradually becomes broad and low and eventually disappears as the bias increases. These phenomena can be explained by the bias-dependent MO levels shown in Fig. 5(b). As mentioned above, the HOMO (HOMO-1) is localized in the left (right) carbon chains. When the bias +Vₚ/2 is applied to the left lead, the electrochemical potential in the left lead is shifted down by Vₚ/2, and the potential in the right lead is shifted up by Vₚ/2 as the bias -Vₚ/2 is applied to the right lead. The HOMO (HOMO-1) shifts down (up) rough following the left (right) lead because these two carbon chains are separated by vacuum barrier. It is clear that the HOMO and HOMO-1 indeed leaves each other when the bias increases, as shown in Fig. 5(b). At zero bias, as mentioned above, the T(Vₚ, E) peak around the Fermi level originate from the resonance transmission between
HOMO and HOMO-1 because the energy difference between them is negligibly small. Due to the effect of coherent tunneling $^{[38]}$, $T(V_b, E)$ peak around the Fermi level will be still present but becomes low and broad when the HOMO and HOMO-1 leaves each other in energy space. This $T(V_b, E)$ peak will eventually disappear when the energy difference of HOMO and HOMO-1 is adequate large. From zero bias to $V_{\text{peak}}$, the increase of transport window predominates transport characteristics and promotes the increase of current. From $V_{\text{peak}}$ to $V_{\text{valley}}$, the energy difference of HOMO and HOMO-1 predominates transport characteristics and reduces the current. Hence, the NDR effect at low bias is present.

**Conclusions:**

In summary, using a first-principles calculations which combine NEGF with DFT, we realize one-dimensional NDR effect by four carbon atom chains, and the possibility of the NDR effect at low bias is increased. Our calculations also reveal that one can adjust the molecular NDR effect at low bias by adjusting the modified radicals, which indicate potential molecular-electronics applications.

**References:**